## NSN 5961-01-502-3723

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-502-3723 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.146 inches **Overall Diameter:** Between 0.063 inches and 0.067 inches **End Application:** F/a-18e/f hornet aircraft; central processor Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-213aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.7 regulator voltage, dc **Current Rating Per Characteristic:** 75.00 milliamperes source cutoff current horsepower metric and 2.00 milliamperes forward current, average peak **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No